



# Product Change Notification - SYST-07RBTD729

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**Date:** 11 Apr 2017  
**Product Category:** Depletion Mode MOSFETs  
**Affected CPNs:**    
**Notification subject:** Data Sheet - DN3135 N-Channel Depletion-Mode Vertical DMOS FET Data Sheet  
**Notification text:** SYST-07RBTD729

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Microchip has released a new DeviceDoc for the DN3135 N-Channel Depletion-Mode Vertical DMOS FET Data Sheet of devices. If you are using one of these devices please read the document located at [DN3135 N-Channel Depletion-Mode Vertical DMOS FET Data Sheet](#).

**Notification Status:** Final

**Description of Change:** 1) Converted Supertex Doc# DSFP-DN3135 to Microchip DS20005703A. 2) Changed the packaging format. 3) Made minor text changes throughout the document.

**Impacts to Data Sheet:** None

**Reason for Change:** To Improve Manufacturability

**Change Implementation Status:** Complete

**Date Document Changes Effective:** 11 Apr 2017

**NOTE:** Please be advised that this is a change to the document only the product has not been changed.

**Markings to Distinguish Revised from Unrevised Devices:** N/A

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**Attachment(s):** [DN3135 N-Channel Depletion-Mode Vertical DMOS FET Data Sheet](#)

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Affected Catalog Part Numbers (CPN)

DN3135NW-8

DN3135NW

DN3135N8-G

DN3135K1-G

## N-Channel Depletion-Mode Vertical DMOS FET

### Features

- High Input Impedance
- Low Input Capacitance
- Fast Switching Speeds
- Low On-resistance
- Free from Secondary Breakdown
- Low Input and Output Leakage

### Applications

- Normally-on Switches
- Solid State Relays
- Converters
- Linear Amplifiers
- Constant-current Sources
- Power Supply Circuits
- Telecommunications

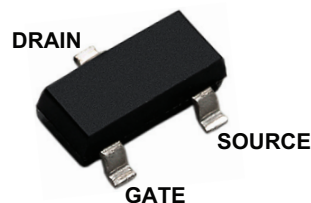
### General Description

The DN3135 is a low-threshold, Depletion-mode (normally-on) transistor that utilizes an advanced vertical DMOS structure and a well-proven silicon gate manufacturing process. This combination produces a device with the power handling capabilities of bipolar transistors and the high input impedance and positive temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, this device is free from thermal runaway and thermally induced secondary breakdown.

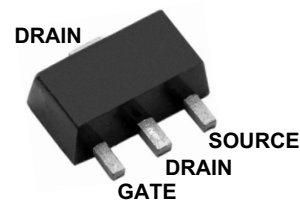
Microchip's vertical DMOS FETs are ideally suited to a wide range of switching and amplifying applications where very low threshold voltage, high breakdown voltage, high input impedance, low input capacitance and fast switching speeds are desired.

### Package Types

**SOT-23 (TO-236AB)**  
(Top view)



**SOT-89 (TO-243AA)**  
(Top view)



See [Table 2-1](#) for pin information.

# DN3135

## 1.0 ELECTRICAL CHARACTERISTICS

### Absolute Maximum Ratings†

Drain-to-source Voltage.....	$BV_{DSX}$
Drain-to-gate Voltage .....	$BV_{DGX}$
Gate-to-source Voltage .....	$\pm 20V$
Operating Ambient Temperature, $T_A$ .....	$-55^{\circ}C$ to $+150^{\circ}C$
Storage Temperature, $T_S$ .....	$-55^{\circ}C$ to $+150^{\circ}C$

† **Notice:** Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

### DC ELECTRICAL CHARACTERISTICS <sup>1</sup>

**Electrical Specifications:** Unless otherwise specified, for all specifications  $T_A = T_J = +25^{\circ}C$ .

Parameter	Sym.	Min.	Typ.	Max.	Unit	Conditions
Drain-to-source Breakdown Voltage	$BV_{DSX}$	350	—	—	V	$V_{GS} = -5V, I_D = 100 \mu A$
Gate-to-source Off Voltage	$V_{GS(OFF)}$	-1.5	—	-3.5	V	$V_{DS} = 15V, I_D = 10 \mu A$
Change in $V_{GS(OFF)}$ with Temperature	$\Delta V_{GS(OFF)}$	—	—	-4.5	mV/ $^{\circ}C$	$V_{DS} = 15V, I_D = 10 \mu A$ ( <b>Note 2</b> )
Gate Body Leakage Current	$I_{GSS}$	—	—	100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
Drain-to-source Leakage Current	$I_{D(OFF)}$	—	—	1	$\mu A$	$V_{DS} = \text{Max rating}, V_{GS} = -5V$
		—	—	1	mA	$V_{DS} = 0.8 \text{ Max Rating}, V_{GS} = -5V, T_A = 125^{\circ}C$ ( <b>Note 2</b> )
Saturated Drain-to-source Current	$I_{DSS}$	180	—	—	mA	$V_{GS} = 0V, V_{DS} = 15V$
Static Drain-to-source On-state Resistance	$R_{DS(ON)}$	—	—	35	$\Omega$	$V_{GS} = 0V, I_D = 150 \text{ mA}$
Change in $R_{DS(ON)}$ with Temperature	$\Delta R_{DS(ON)}$	—	—	1.1	%/ $^{\circ}C$	$V_{GS} = 0V, I_D = 150 \text{ mA}$ ( <b>Note 2</b> )

**Note 1:** All DC parameters are 100% tested at  $25^{\circ}C$  unless otherwise stated. Pulse test: 300  $\mu s$  pulse, 2% duty cycle.

**2:** Specification is obtained by characterization and is not 100% tested.

## AC ELECTRICAL CHARACTERISTICS <sup>2</sup>

Electrical Specifications: Unless otherwise specified, for all specifications $T_A = T_J = +25^\circ\text{C}$ .						
Parameter	Sym.	Min.	Typ.	Max.	Unit	Conditions
Forward Transconductance	$G_{FS}$	140	—	—	mmho	$V_{DS} = 10\text{V}, I_D = 100\text{ mA}$
Input Capacitance	$C_{ISS}$	—	60	120	pF	$V_{GS} = -5\text{V},$ $V_{DS} = 25\text{V},$ $f = 1\text{ MHz}$
Common Source Output Capacitance	$C_{OSS}$	—	6	15		
Reverse Transfer Capacitance	$C_{RSS}$	—	3	10		
Turn-on Delay Time	$t_{d(ON)}$	—	—	10	ns	$V_{DD} = 25\text{V},$ $I_D = 150\text{ mA},$ $R_{GEN} = 25\Omega,$ $V_{GS} = 0\text{V to } -10\text{V}$
Rise Time	$t_r$	—	—	15		
Turn-off Delay Time	$t_{d(OFF)}$	—	—	15		
Fall Time	$t_f$	—	—	20		
DIODE PARAMETER						
Diode Forward Voltage Drop	$V_{SD}$	—	—	1.8	V	$V_{GS} = -5\text{V}, I_{SD} = 150\text{ mA}$ (Note 1)
Reverse Recovery Time	$t_{rr}$	—	800	—	ns	$V_{GS} = -5\text{V}, I_{SD} = 150\text{ mA}$ (Note 2)

**Note 1:** All DC parameters are 100% tested at  $25^\circ\text{C}$  unless otherwise stated. Pulse test: 300  $\mu\text{s}$  pulse, 2% duty cycle.

**2:** Specification is obtained by characterization and is not 100% tested.

## TEMPERATURE SPECIFICATIONS

Parameter	Sym.	Min.	Typ.	Max.	Unit	Conditions
TEMPERATURE RANGE						
Operating Ambient Temperature	$T_A$	-55	—	+150	$^\circ\text{C}$	
Storage Temperature	$T_S$	-55	—	+150	$^\circ\text{C}$	
PACKAGE THERMAL RESISTANCE						
SOT-23	$\theta_{JA}$	—	203	—	$^\circ\text{C/W}$	
SOT-89	$\theta_{JA}$	—	133	—	$^\circ\text{C/W}$	

## THERMAL CHARACTERISTICS

Package	$I_D^{(1)}$ (Continuous) (mA)	$I_D$ (Pulsed) (mA)	Power Dissipation at $T_A = 25^\circ\text{C}$ (W)	$I_{DR}^{(1)}$ (mA)	$I_{DRM}$ (mA)
SOT-23	72	300	0.36	72	300
SOT-89	135	300	1.3 <sup>(2)</sup>	135	300

**Note 1:**  $I_D$  (continuous) is limited by maximum  $T_J$ .

**2:** Mounted on FR4 board, 25 mm x 25 mm x 1.57 mm

# DN3135

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## 2.0 PIN DESCRIPTION

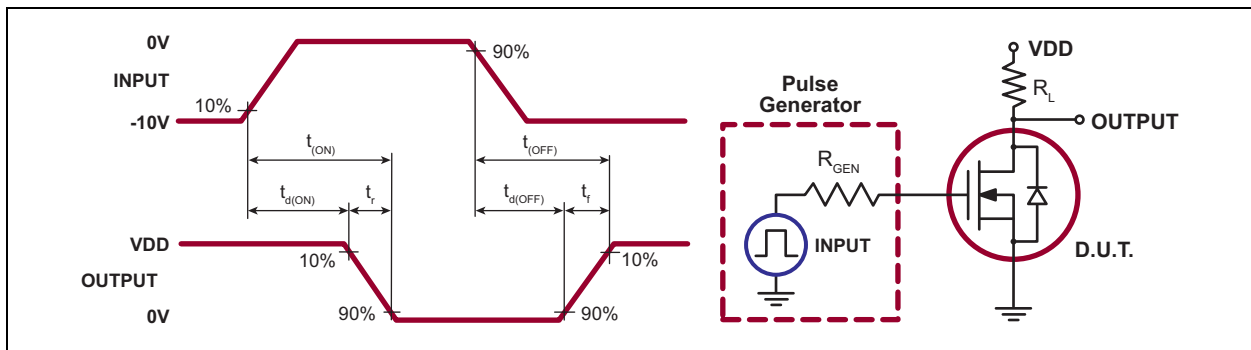
Table 2-1 shows the description of pins in DN3135 SOT-23 and SOT-89. Refer to [Package Types](#) for the location of pins.

**TABLE 2-1: PIN FUNCTION TABLE**

SOT-23 Pin Number	SOT-89 Pin Number	Pin Name	Description
1	1	Gate	Gate
2	3	Source	Source
3	2, 4	Drain	Drain

## 3.0 FUNCTIONAL DESCRIPTION

Figure 3-1 illustrates the switching waveforms and test circuit for DN3135.



**FIGURE 3-1:** Switching Waveforms and Test Circuit.

## PRODUCT SUMMARY

$BV_{DSX}/BV_{DGX}$ (V)	$R_{DS(ON)}$ (Maximum) ( $\Omega$ )	$I_{DSS}$ (Minimum) (mA)
350	35	180

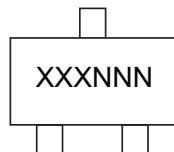
# DN3135

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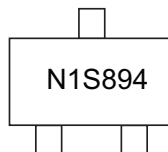
## 4.0 PACKAGING INFORMATION

### 4.1 Package Marking Information

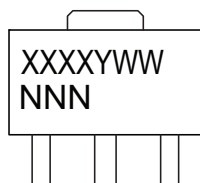
3-lead SOT-23



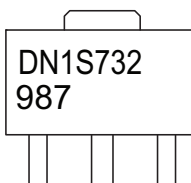
Example



3-lead SOT-89



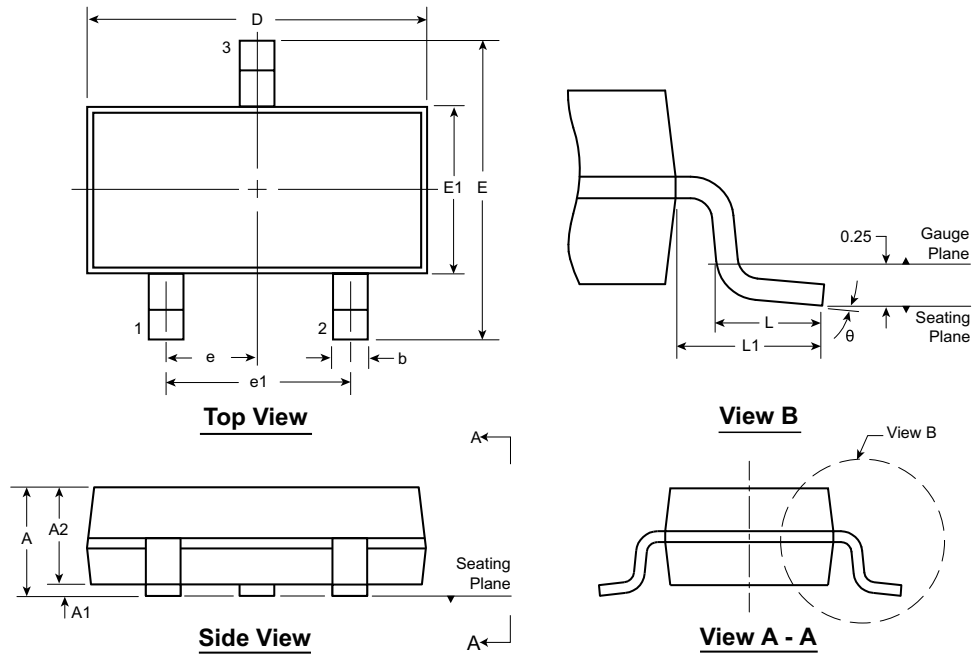
Example



<b>Legend:</b>	XX...X	Product Code or Customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week '01')
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC <sup>®</sup> designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.
<b>Note:</b>	In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for product code or customer-specific information. Package may or not include the corporate logo.	



## 3-Lead TO-236AB (SOT-23) Package Outline (K1/T) 2.90x1.30mm body, 1.12mm height (max), 1.90mm pitch



Note: For the most current package drawings, see the Microchip Packaging Specification at \*/packaging.

Symbol	A	A1	A2	b	D	E	E1	e	e1	L	L1	$\theta$
Dimension (mm)	MIN	0.89	0.01	0.88	0.30	2.80	2.10	1.20	0.95 BSC	1.90 BSC	0.20 <sup>†</sup>	0°
	NOM	-	-	0.95	-	2.90	-	1.30			0.54	-
	MAX	1.12	0.10	1.02	0.50	3.04	2.64	1.40			REF	8°

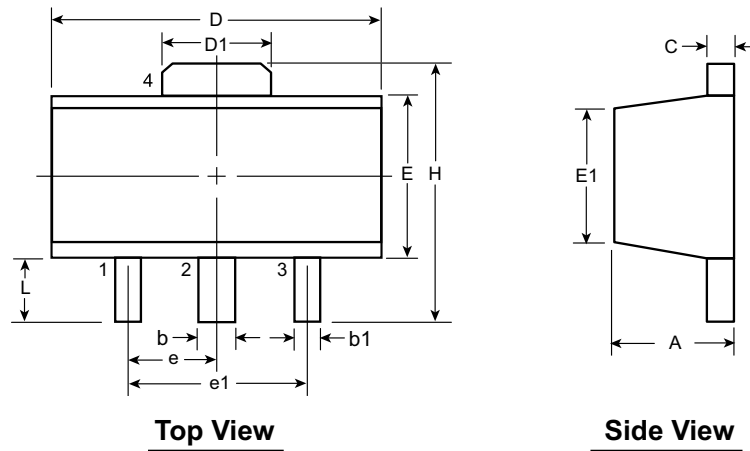
JEDEC Registration TO-236, Variation AB, Issue H, Jan. 1999.

<sup>†</sup> This dimension differs from the JEDEC drawing.

**Drawings not to scale.**

# DN3135

## 3-Lead TO-243AA (SOT-89) Package Outline (N8)



Note 6: For the most current package drawings see the Microchip Packaging Specification at [www.microchip.com/packaging](http://www.microchip.com/packaging).

Symbol	A	b	b1	C	D	D1	E	E1	e	e1	H	L		
Dimensions (mm)	MIN	1.40	0.44	0.36	0.35	4.40	1.62	2.29	2.00†	1.50 BSC	3.00 BSC	3.94	0.73†	
	NOM	-	-	-	-	-	-	-	-			-	-	-
	MAX	1.60	0.56	0.48	0.44	4.60	1.83	2.60	2.29			-	-	4.25

JEDEC Registration TO-243, Variation AA, Issue C, July 1986.

† This dimension differs from the JEDEC drawing

Drawings not to scale.

## APPENDIX A: REVISION HISTORY

### Revision A (April 2017)

- Converted Supertex Doc# DSFP-DN3135 to Microchip DS20005703A
- Changed the packaging format
- Made minor text changes throughout the document

# DN3135

## PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

<u>PART NO.</u>	<u>XX</u>	-	<u>X</u>	-	<u>X</u>
Device	Package Options		Environmental		Media Type
Device:	DN3135	=	N-Channel Depletion-Mode Vertical DMOS FET		
Packages:	K1	=	3-lead SOT-23		
	N8	=	3-lead SOT-89		
Environmental:	G	=	Lead (Pb)-free/RoHS-compliant Package		
Media Type:	(blank)	=	3000/Reel for a K1 Package 2000/Reel for an N8 Package		

**Examples:**

a) DN3135K1-G: N-Channel Depletion-Mode Vertical DMOS FET, 3-lead SOT-23, 3000/Reel

b) DN3135N8-G: N-Channel Depletion-Mode Vertical DMOS FET, 3-lead SOT-89, 2000/Reel

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